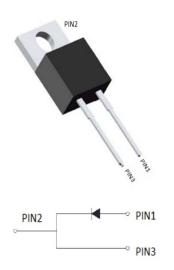






Silicon Carbide Schottky Diode

V_{RRM}	650 V
I _{F (135°C)}	10 A
Qc	25 nC



Foatures

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery voltage
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

• Package: TO-220AC

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant, halogen-free

• Terminals: Tin plated leads

• Polarity: As marked

■Maximum Ratings (T_c=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D106506PQG2
Reverse voltage (repetitive peak) @ T _i =25°C	V_{RRM}	٧	650
Reverse voltage (Surge Peak) @ T _j =25°C	V_{RSM}	V	650
Reverse voltage (DC) @ T _j =25°C	V_{DC}	V	650
Continuous forward current @ T _c =25°C			21
Continuous forward current @ T _c =135°C	I _F	Α	10
Continuous forward current @ T _c =157°C			6
Non-repetitive peak forward surge current @ T _c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	65
Power Dissipation@ T _c =25°C	P _{TOT}	w	84
Power Dissipation@ T _c =110°C	Гтот	VV	36
i²t Value@ Tc=25°C ,tp=10ms	∫i²dt	A ² S	21
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175

YJD106506PQG2

■Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drep	V _F	V	I _F =6A, T _j =25°C	1.31	1.5
Forward voltage drop	V _F	V	I _F =6A, T _j =175°C	1.65	-
Poverse legkage current	I _R µA		V _R =650V, T _j =25°C	0.5	25
Reverse leakage current		μΑ	V _R =650V, T _j =175°C	5	-
Total capacitive charge	Q _C	nC	V_R =400V, T_j =25°C , QC = $\int_0^{VR}C(V)dV$	25	-
			V _R =0V, f=1MHZ	378	-
Total capacitance	С	pF	V _R =200V, f=1MHZ	51	-
			V _R =400V, f=1MHZ	49	-
Capacitance Stored Energy	Ec	μJ	V _R =400V	3	-

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	Value
Thermal resistance	R _{eJ-C}	°CW	1.78

■Typical Characteristics

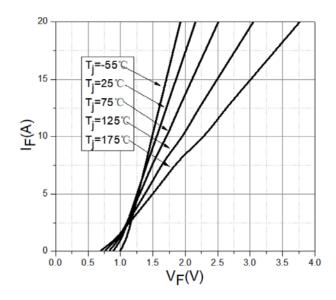


Figure 1. Forward Characteristics

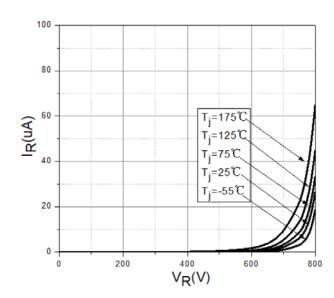
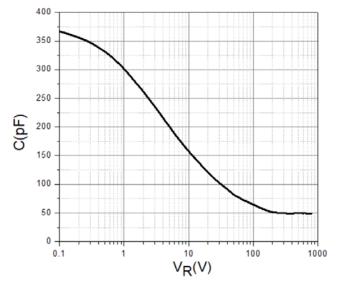


Figure 2. Reverse Characteristic





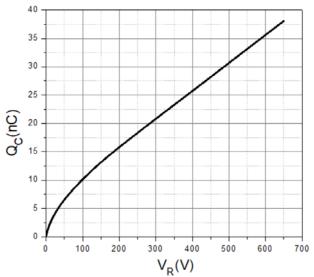
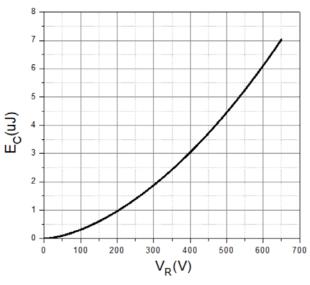
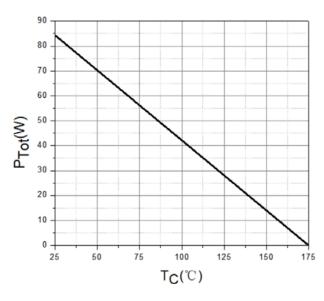
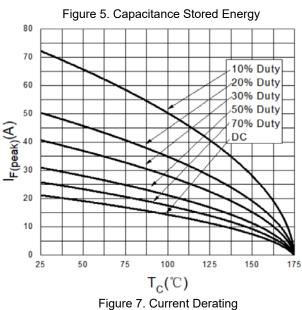


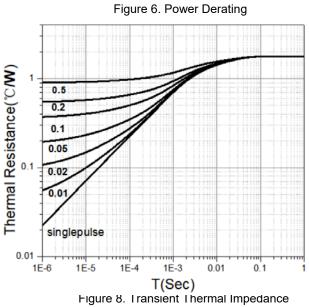
Figure 3. Capacitance vs. Reverse Voltage

Figure 4. Total Capacitance Charge vs. Reverse Voltage







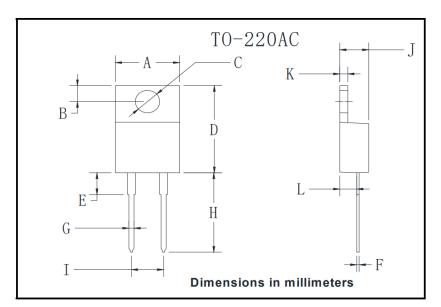


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■Outline Dimensions



TO-220AC				
Dim	Min	Max		
Α	9.95	10.35		
В	2.55	2.95		
С	3.75	4.05		
D	14.95	15.25		
Е	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.3	13.9		
1	4.86	5.26		
J	4.38	4.78		
K	1.14	1.4		
L	2.37	2.79		



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